NSN 5961-00-139-1960

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-139-1960 **Inclosure Material:** Metal **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.085 inches and 0.107 inches **End Application:** 2forrestal class cv, wasp class lhd, whidbey island class lsd, sirius class t-afs 8, oliver perry class ffg, nimitz class cvn, tarawa class lha, kilauea class t-ae 26, spruance class dd (963). General purpose electronic test equipment (gpete). **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Voltage Rating In Volts Per Characteristic: 75.0 regulator voltage **Power Rating Per Characteristic:** 0.4 watts small-signal input power, common-collector absolute **Special Features:** Weapon system essential; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No